

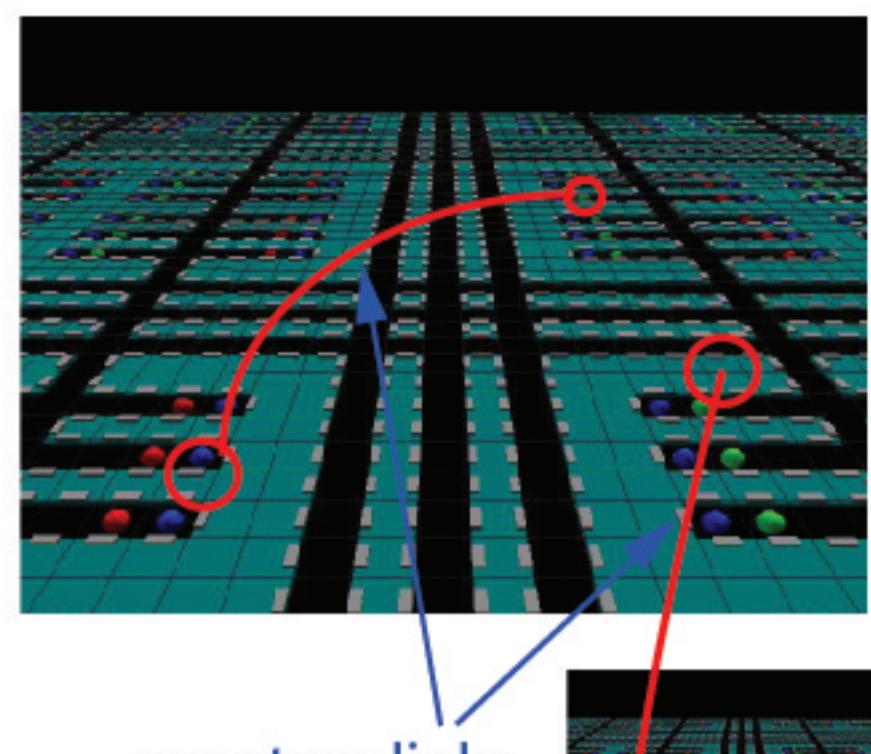
A micro-fabricated surface ion trap on a high reflectivity optical mirror

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Introduction

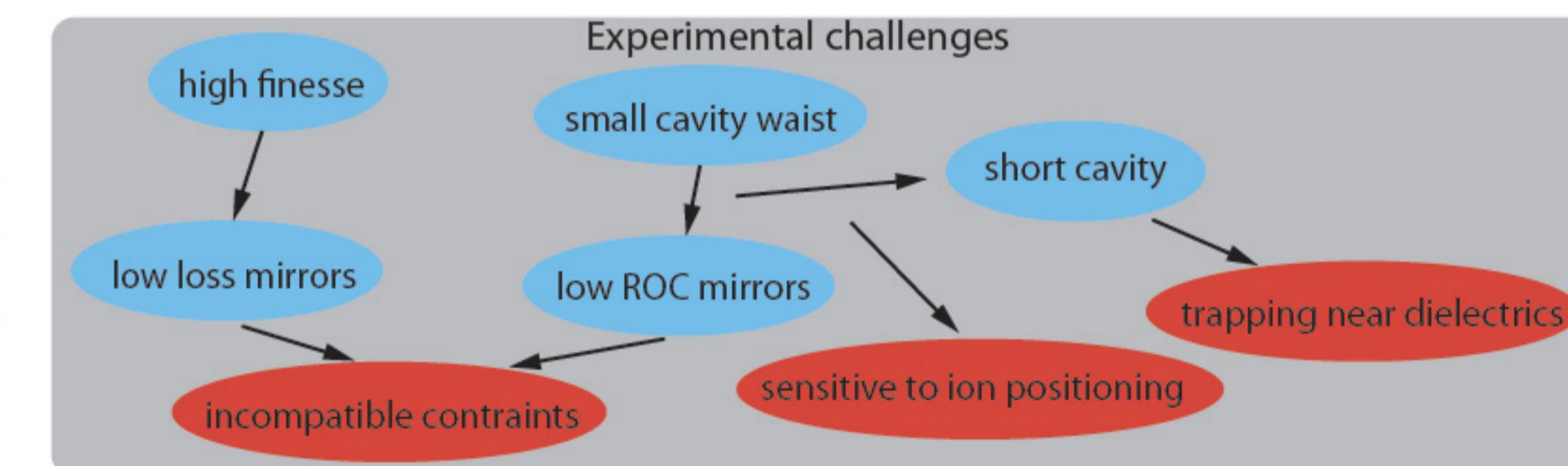
Motivation:
Multi-qubit operations in a large scale ion trap quantum computer must involve interconnecting trapped ions at several designated sites, without cross-talk to other ions. One suitable interconnection method maps quantum states of ions to photons, using strong atom-light interactions. This can be accomplished by coupling ions to high finesse optical cavities.



- Challenges:**
- the trapping potential can be perturbed in the presence of dielectric mirrors, which affect both the trap rf-fields and allows build-up of stray charges on the substrates via light-induced charging;
 - when close to material surfaces, anomalous heating of ions may lead to rapid decoherence of their motional states;
 - the need for scalable trap technology imposes severe design and fabrication constraints on the experiment.

$$\text{Strong coupling criteria: } g_0 > K, G \\ \text{Cooperativity } C = \frac{g_0^2}{K\gamma} = \frac{6F\lambda}{\pi^3 W_0^2}$$

Figure of merit:
Fidelity of ion-photon $\sim \frac{C}{C+1}$



This work:
Here we present a new approach for integrating an optical cavity into an ion trap, by employing a surface electrode ion trap fabricated on top of a high reflectivity mirror. We evaluate optical losses incurred by the micro-fabrication, characterize basic trap performance, and describe plans for incorporating a second low ROC mirror to form a high finesse cavity.

Road map

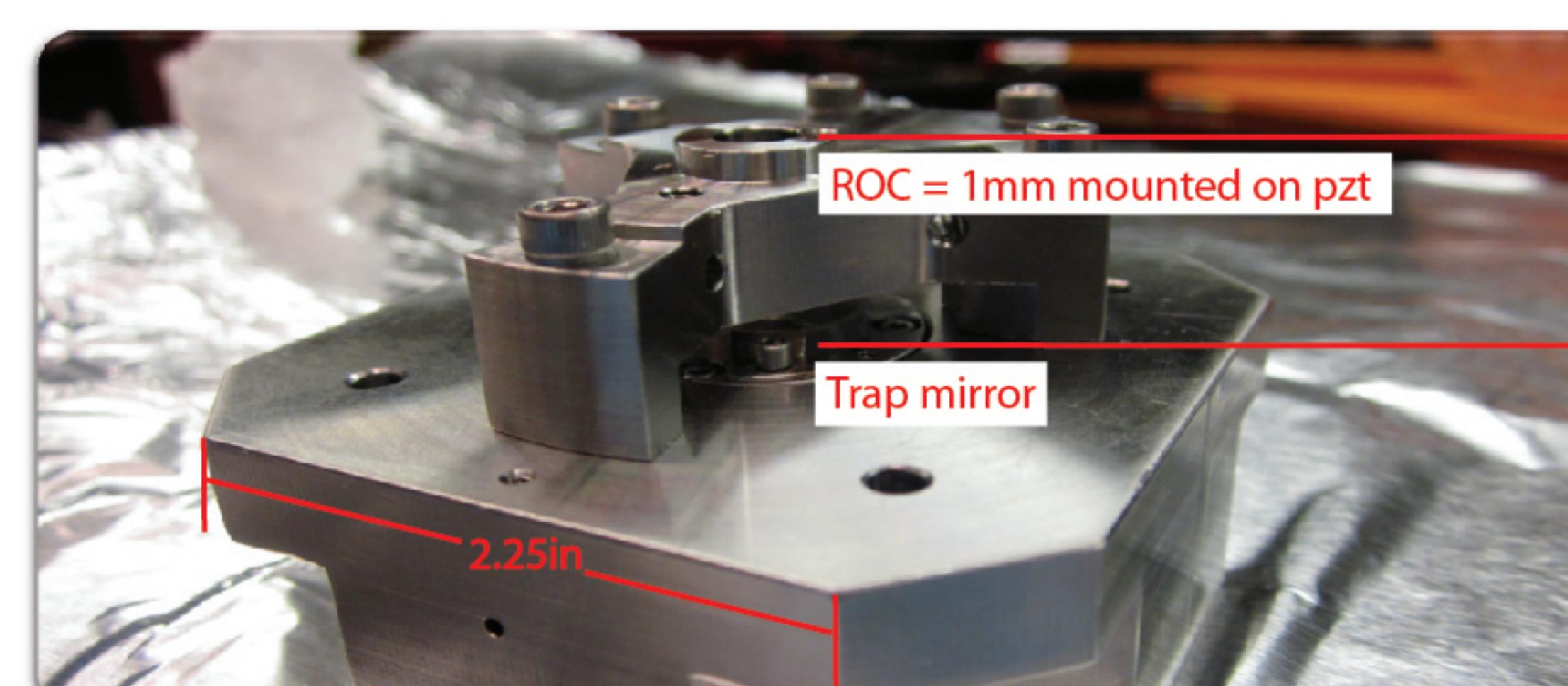
Ion trap on a high finesse mirror

- Fabrication of surface electrode ion trap on high-finesse mirror while leaving aperture in electrode underneath ion for optical access to mirror
- Study of ion trapping ~150um above surface of mirror
- Post-fab mirror loss characterization

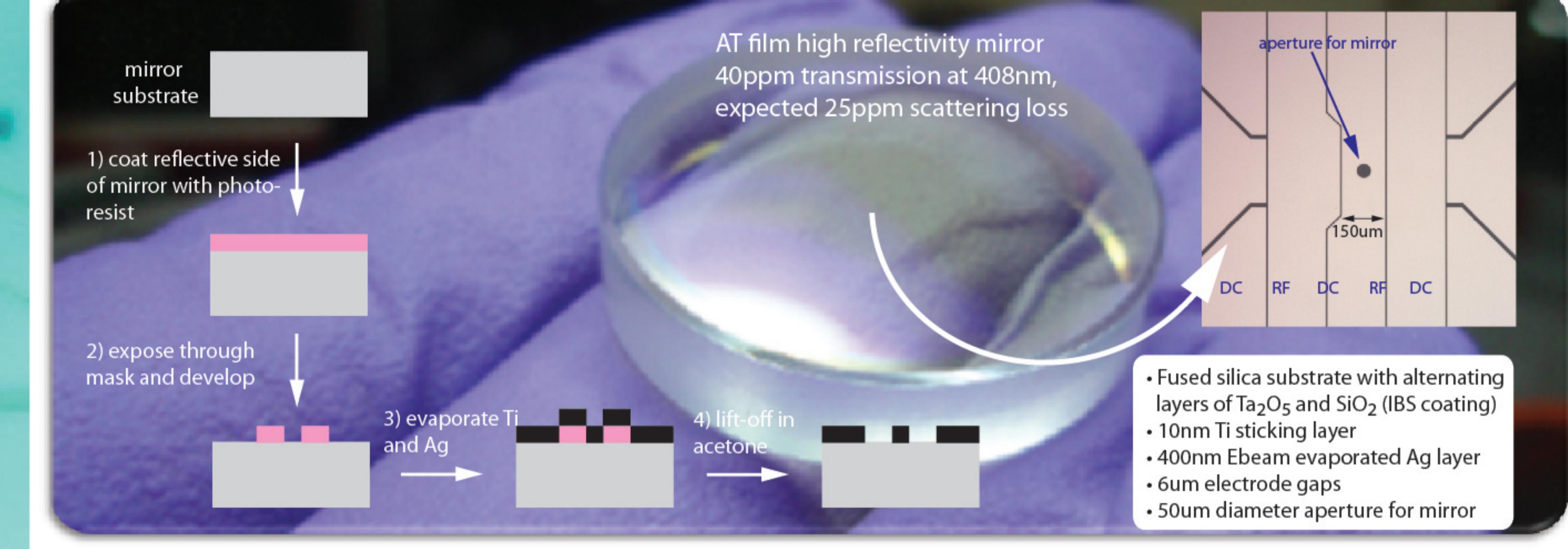
Laser machined low ROC mirror

- Laser machined micro-mirrors with ROC = 50um-1100um for micro-cavity
- Cavity finesse characterization

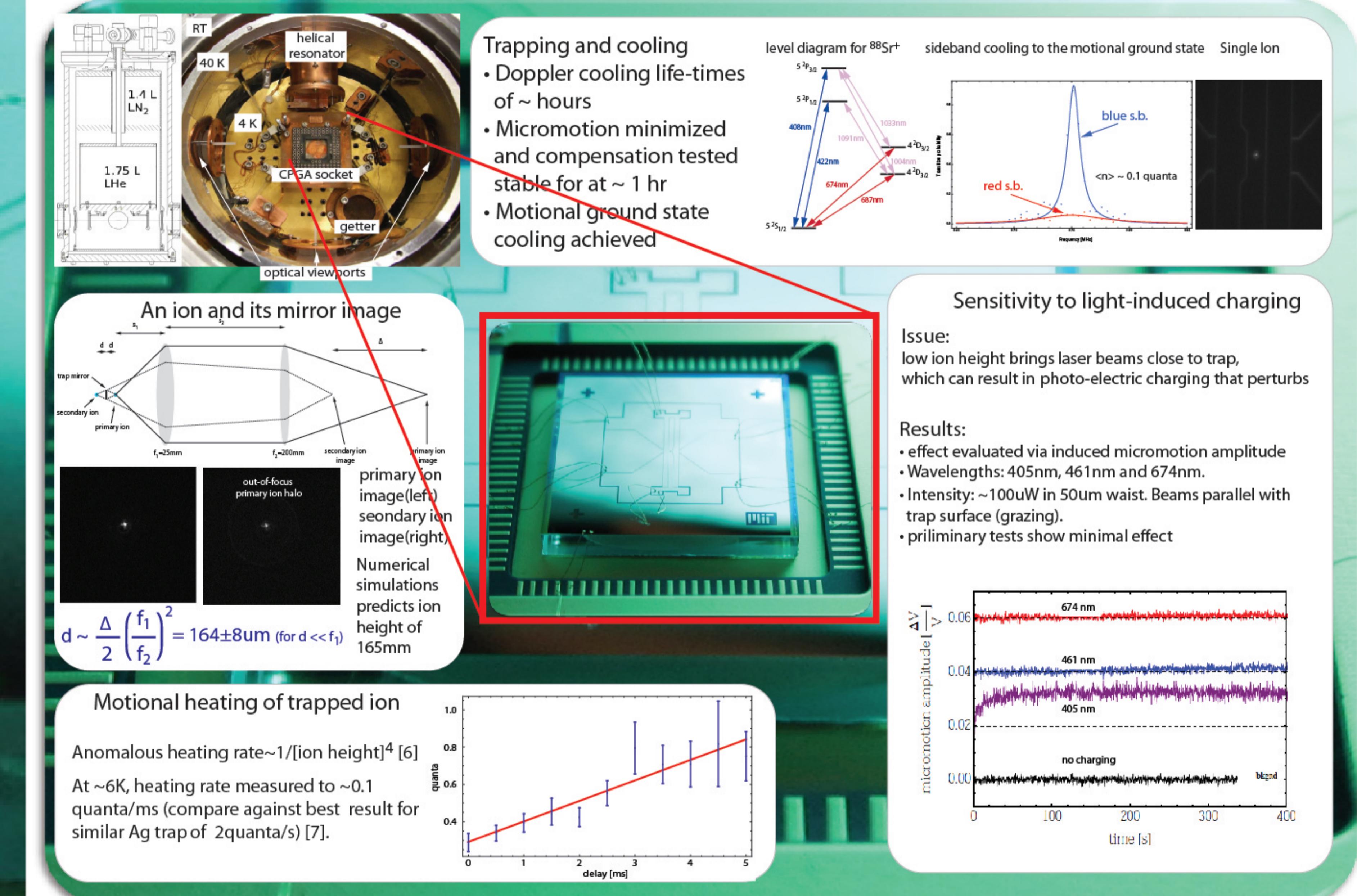
Future cavity + ion system



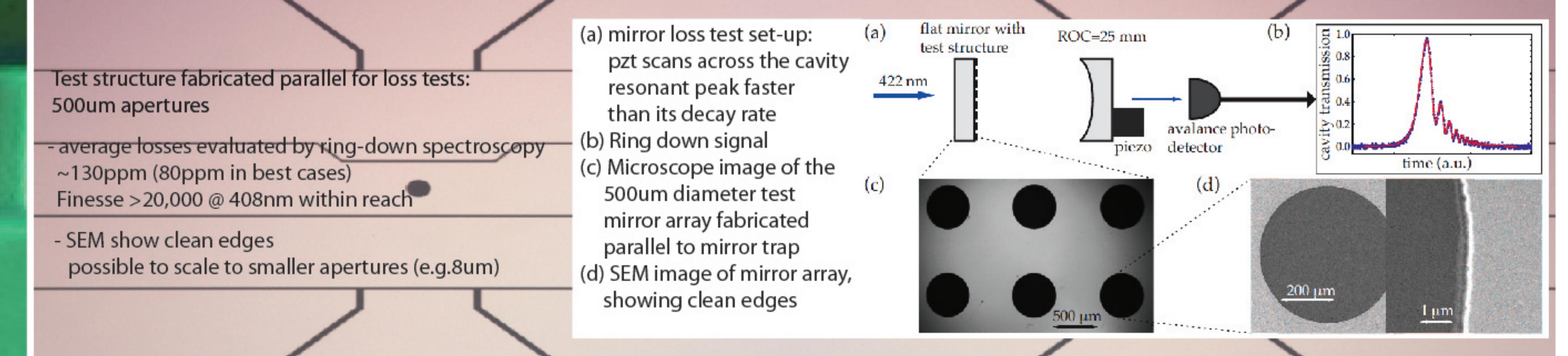
Microfabrication of a surface electrode ion trap on a dielectric mirror



Trapping ions above the surface of a dielectric mirror



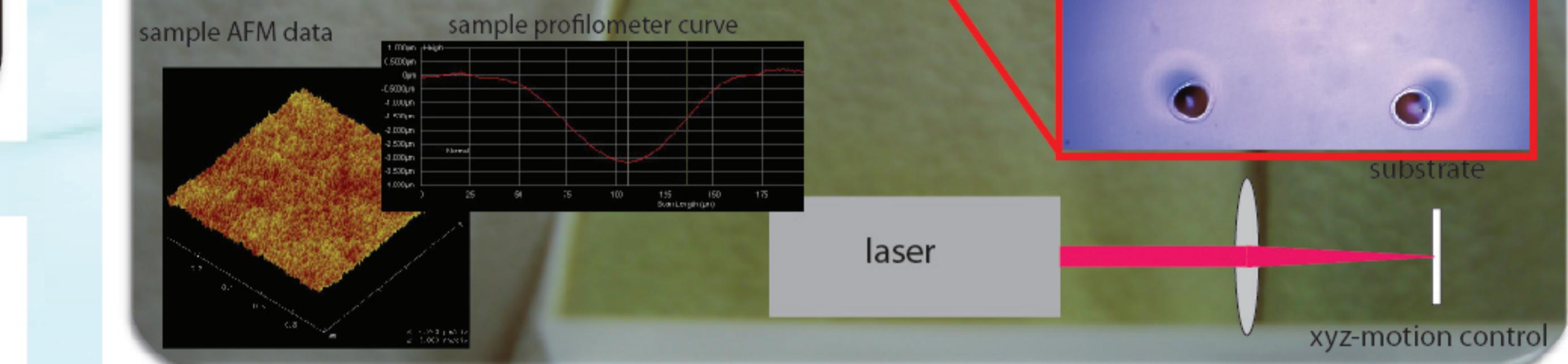
Post-fab mirror loss characterization



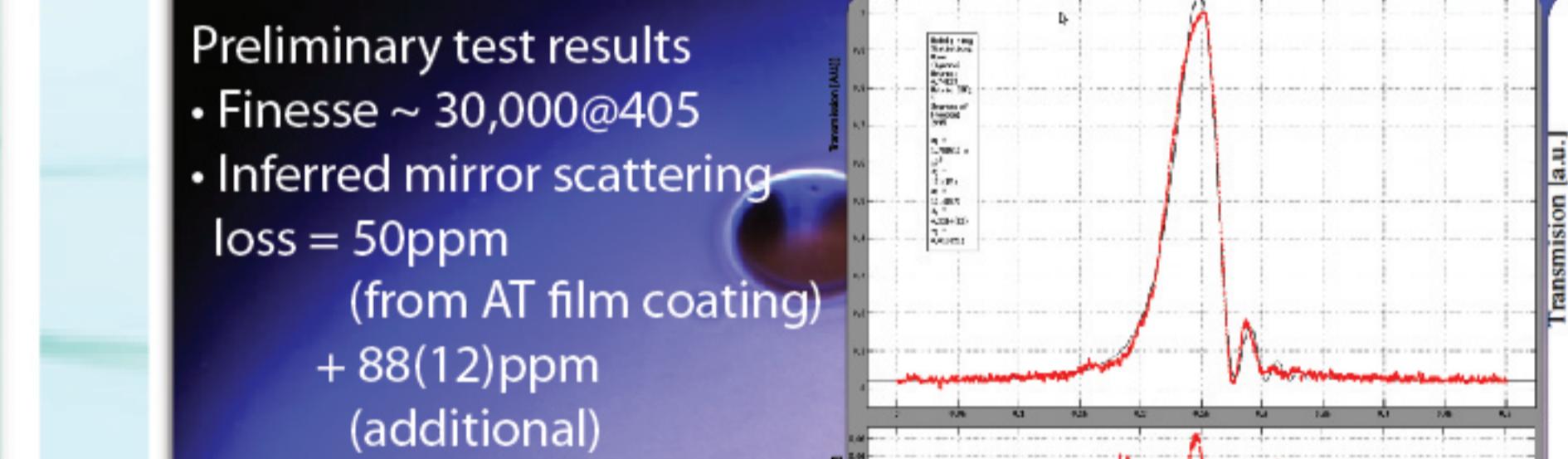
Fabrication of low ROC mirrors

- Motivation:**
- Commercial low loss mirrors (super-polished) presently limited to radius of curvature (ROC) of ~25mm
 - Resulting waist in confocal cavity geometry ~ 25-50mm
- New approach [9]:
- high-power laser causes evaporation and melting of glass substrate
 - mirror shape reflects the laser intensity profile
 - ROC controlled via waist of laser
 - mirror diameter and depth controlled by laser power

- Results**
- ROC varied from 50um to 1100um
 - Measured surface roughness ~ 2.7 Angstrom



Micro-mirror loss characterization

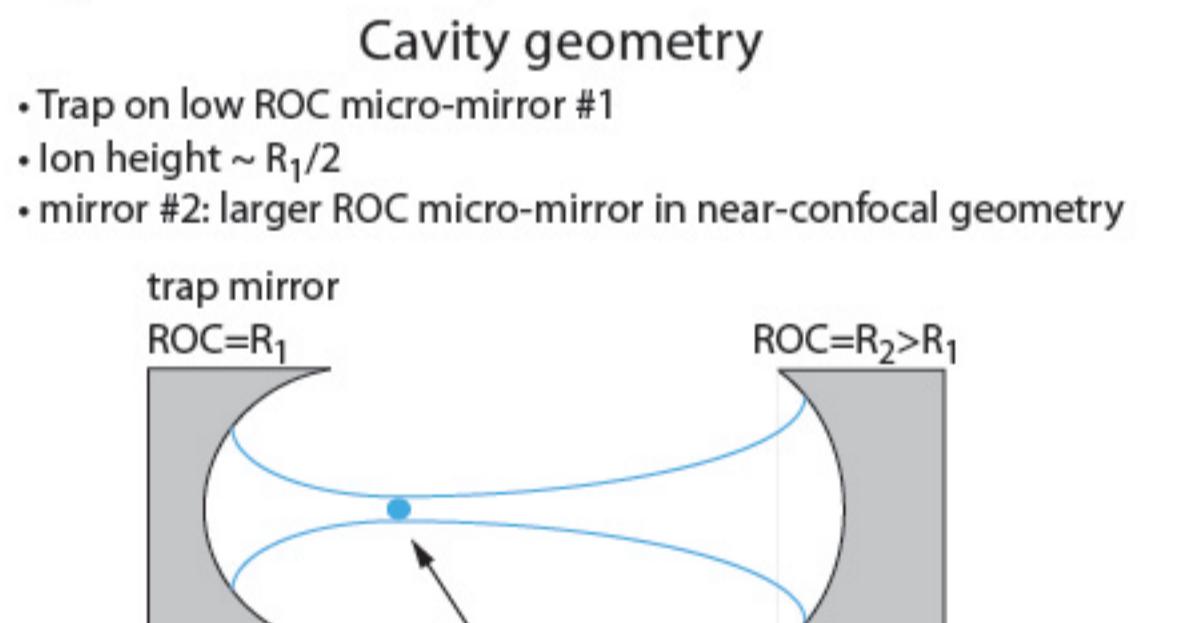


Trap + resonator: design and predicted performance

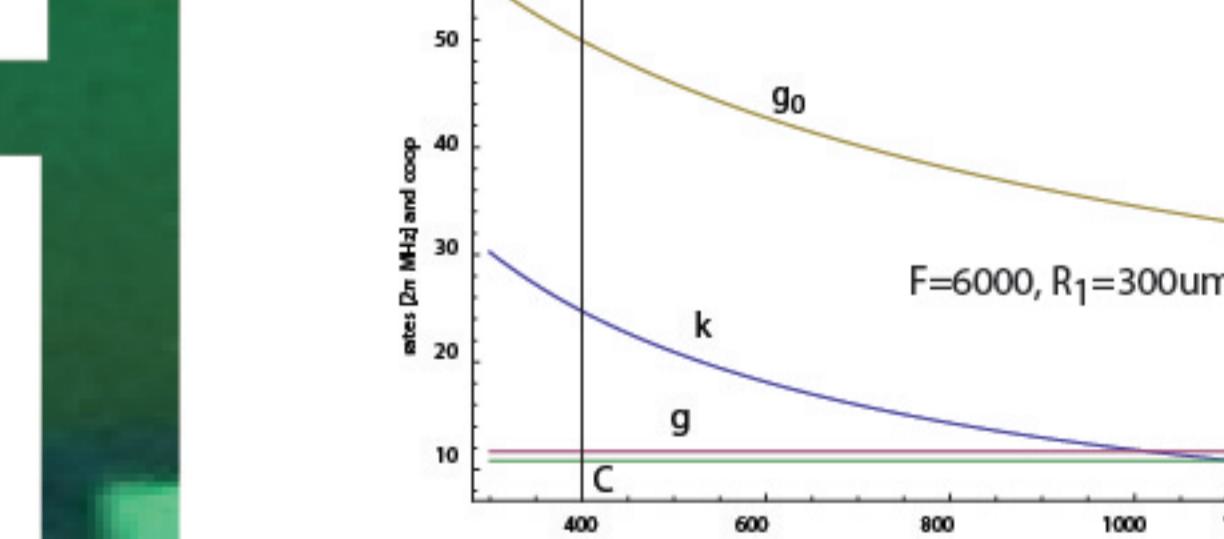
Design parameters:

- wavelength: 408nm
- $R_1=300\mu\text{m}$
- $R_2=1000\mu\text{m}$
- Transmission mirror 1 = 40ppm
- Transmission mirror 2 = 800ppm
- absorption and scatter losses pr mirror: 100ppm
- Finesse: 6000
- cavity length: 1.1mm
- waist: 5um
- cooperativity: 8
- $g_0=2\pi 32\text{MHz}$
- $\kappa=2\pi 9\text{MHz}$
- $\gamma=2\pi 11\text{MHz}$

Cavity geometry

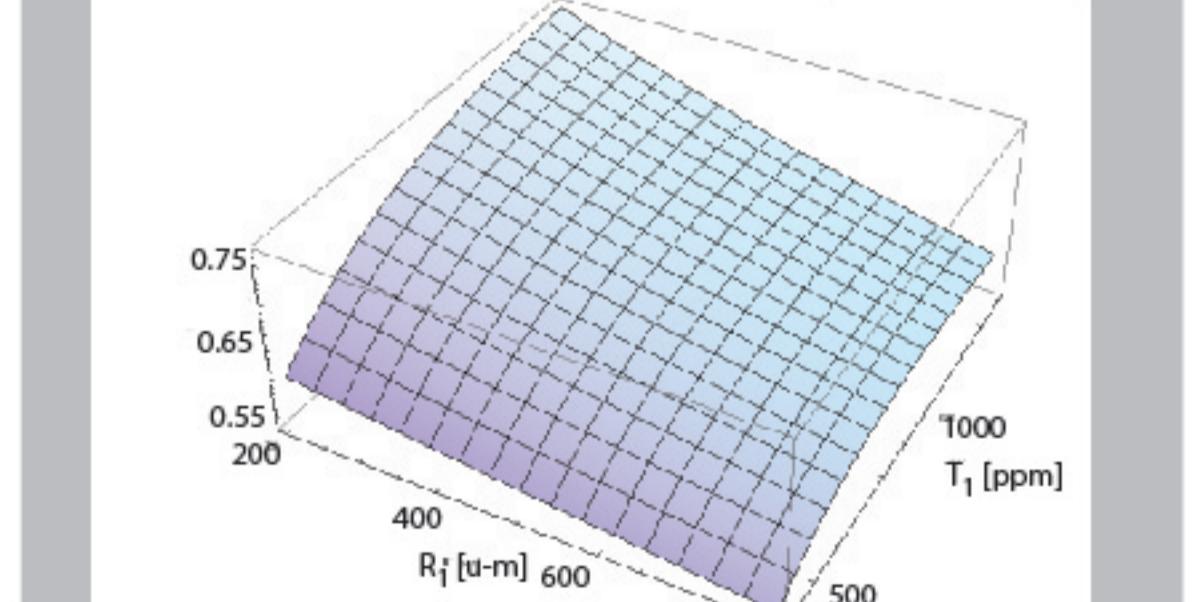


Dependence on R_2



Fidelity of ion-photon mapping:

$$\sim \frac{C}{C+1} \times \frac{T_1}{T_1+T_2+2\text{Loss}} \sim 0.7$$



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